LV8139JA

Sine wave PWM Drive, Pre drive IC, for Brushless Motor Drive

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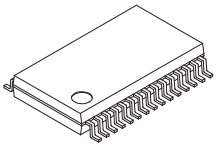

SSOP30 (275mil)

Overview

The LV8139JA is a PWM system pre driver IC designed for three-phase brushless motors.

This IC reduces motor driving noise by using a high-efficiency, sine wave PWM drive type.

It incorporates a full complement of protection circuits and, by combining it with a hybrid IC in the STK611 or STK5C4 series, the number of components used can be reduced and a high level of reliability can be achieved. Furthermore, its power-saving mode enables the power consumption in the standby mode to be reduced to zero. This IC is optimally suited for driving various large-size motors such as those used in air conditioners and hot-water heaters.

Features

- Three-phase bipolar drive
- Sine wave PWM drive
- Drive phase setting function (Set 0-58 degrees 32 steps: There is an adjustment function corresponding to the CTL pin input)
- Supports power saving mode(power saving mode at CTL pin voltage of 0.95V (typ) or less; I_{CC} = 0mA, HB pin turned off)
- Supports bootstrap
- Automatic recovery type constraint protection circuit
- Forward/reverse switching circuit, Hall bias pin
- Current limiter circuit, low-voltage protection circuit, and thermal shutdown protection circuit
- FG1 and FG3 output (360-degree electrical angle/1 pulse and 3 pulses)

Typical Applications

- Air Purifier
- Clothes Dryer
- Air conditioners
- Consumer

GENERIC MARKING DIAGRAM*

XXXXX = Specific Device Code
Y = Year
M = Month
DDD = Additional Traceability Data

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “ ▪”, may or may not be present.

ORDERING INFORMATION

Ordering Code:
LV8139JA-AH

Package
SSOP30 (275mil)
(Pb-Free / Halogen Free)

Shipping (Qty / packing)
1000 / Tape & Reel

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
http://www.onsemi.com/pub_link/Collateral/BRD8011-D.PDF

April 2016- Rev. 1
Publication Order Number:
LV8139JA/D

Specifications

Absolute Maximum Ratings at Ta = 25°C (Note 1)

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V_{CC} max	V_{CC} pin	18	V
Output current	I_O max		15	mA
Allowable power dissipation	Pd max1	Independent IC	0.45	W
	Pd max2	Mounted on a specified circuit board. (Note 2)	1.05	W
CTL pin applied voltage	V_{CTL} max		18	V
FG1,FG3 pin applied voltage	$V_{FG}1$ max $V_{FG}3$ max		18	V
Junction temperature	Tj max		150	°C
Operating temperature	Topr		-40 to +105	°C
Storage temperature	Tstg		-55 to +150	°C

1. Stresses exceeding those listed in the Absolute Maximum Rating table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
2. Specified circuit board : 114.3mm × 76.1mm × 1.6mm, glass epoxy

Recommendation Operating Range at Ta = 25°C (Note 3)

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage range	V_{CC}		9.5 to 16.5	V
VREG5 pin output current	I_{REG}		-10	mA
HB pin output current	I_{HB}		-30	mA
FG1,FG3 pin output current	$I_{FG}1$, $I_{FG}3$		10	mA

3. Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

Electrical Characteristics at Ta = 25°C, V_{CC} = 15V (Note 4)

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Supply current 1	$I_{CC}1$			4	6	mA
Supply current 2	$I_{CC}2$	At stop (CTL < VIL1)		0	10	μA
Output Block (Pin HIN1, HIN2, HIN3, LIN1, LIN2 and LIN3)						
High level output voltage	V_{HO}	I_O = -10mA	VREG-0.40	VREG-0.25		V
Upper output ON resistance	$R_{ON}H$	I_O = -10mA		25	40	Ω
Low level output voltage	V_{LO}	I_O = 10mA		0.15	0.25	V
Lower output ON resistance	$R_{ON}L$	I_O = 10mA		15	25	Ω
Output leakage current	$I_O$leak				10	μA
Bootstrap charge pulse width	Tboot		1.6	2.5	3.4	μs
Output minimum dead time	Tdt		1.6	2.5	3.4	μs
5V Constant Voltage Output (VREG5 pin)						
Output voltage	VREG	I_O = -5mA	4.7	4.9	5.1	V
Voltage fluctuation	ΔV (REG1)	V_{CC} = 9.5 to 16.5V, I_O = -5mA			100	mV
Load fluctuation	ΔV (REG2)	I_O = -5 to -10mA			100	mV
Hall Amplifier (Pin $IN1^+$, $IN1^-$, $IN2^+$, $IN2^-$, $IN3^+$ and $IN3^-$)						
Input bias current	IB (HA)		-1		0	μA
Common-mode input voltage range 1	VICM1	When a Hall element is used	0.3		VREG-1.8	V
Common-mode input voltage range 2	VICM2	Single-sided input bias mode (when a Hall IC is used)	0		VREG	V
Hall input sensitivity	VHIN	Sine wave, Hall element offset = 0V	80			mVp-p
Hysteresis width	$ΔV_{IN}$ (HA)		15	30	45	mV
Input voltage Low → High	VSLH		5	15	25	mV
Input voltage High → Low	VSHL		-25	-15	-5	mV

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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
CSD Oscillator Circuit (CSD pin)						
High level output voltage	V_{OH} (CSD)		2.75	2.95	3.15	V
Low level output voltage	V_{OL} (CSD)		0.85	1.05	1.25	V
Amplitude	V (CSD)		1.7	1.9	2.1	Vp-p
External capacitor charging current	ICHG1 (CSD)	VCHG1 = 2.0V	-14	-10	-6	μA
External capacitor discharging current	ICHG2 (CSD)	VCHG2 = 2.0V	6	10	14	μA
Lock detection ON/OFF time ratio	LRTO	Drive OFF/drive ON		11		
PWM Oscillator (PWM pin)						
High level output voltage	V_{OH} (PWM)		3.3	3.5	3.7	V
Low level output voltage	V_{OL} (PWM)		1.3	1.5	1.7	V
Amplitude	V (PWM)		1.8	2.0	2.2	Vp-p
Oscillation frequency	f (PWM)	C = 2200pF, R = 15kΩ (design target value)		17.3		kHz
Current Limiter Operation (RF pin)						
Limiter voltage	VRF		0.225	0.25	0.275	V
Thermal Shutdown Protection Operation						
Thermal shutdown protection operating temperature	TSD	Design target value (Note 5) (junction temperature)	150	175		°C
Hysteresis width	ΔTSD	Design target value (Note 5) (junction temperature)		35		°C
TH pin						
Protection start voltage	VTH		0.50	0.65	0.80	V
Hysteresis width	ΔVTH		0.32	0.42	0.52	V
HB pin						
Output ON resistance	R_{ON} (HB)	IHB = -10mA		10	20	Ω
Output leakage current	I_L (HB)	Power saving mode V_{CC} = 15V			10	μA
Low Voltage Protection Circuit (detecting V_{CC} voltage)						
Operation voltage	VSD		7.4	7.9	8.4	V
Hysteresis width	ΔVSD		0.35	0.5	0.65	V
FG1 FG3 Pin						
Output ON resistance	R_{ON} (FG)	IFG = 5mA		40	60	Ω
Output leakage current	I_L (FG)	VFG = 18V			10	μA
CTL Amplifier (drive mode)						
Input voltage range	V_{IN} (CTL)		0		V_{CC}	V
High level input voltage	V_{IH} (CTL)	HIN pin PWM ON duty 100%	4.4	4.6	4.8	V
Middle level input voltage 1 (At drive start)	$V_{IM}1$ (CTLI)	HIN pin PWM ON duty 0%	2.15	2.35	2.55	V
Middle level input voltage 2 (During drive)	$V_{IM}2$ (CTLI)	HIN pin PWM ON duty 0%	1.9	2.1	2.3	V
Input current (During drive in 120-degree current-carrying mode)	$I_{IH}1$ (CTLI)	VCTL = 3.5V	13	25	37	μA
Input current (During drive in sine wave current-carrying mode)	$I_{IH}2$ (CTLI)	VCTL = 3.5V	10	20	30	μA
CTL Amplifier (power saving mode)						
Low level input voltage	$V_{IL}1$ (CTL)	Power saving mode	0.75	0.95	1.15	V
Hysteresis width	ΔCTL		0.15	0.35	0.55	V

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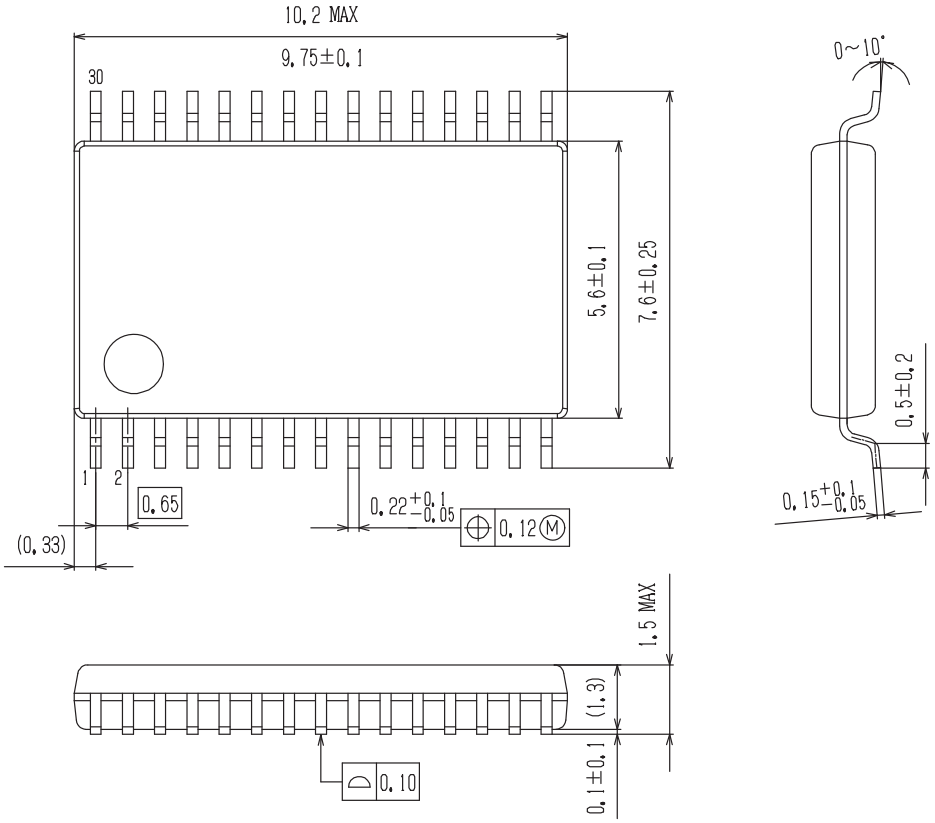
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
F/R Pin						
High level input voltage range	V_{IH} (FR)		3.0		VREG	V
Low level input voltage range	V_{IL} (FR)		0		0.7	V
Input open voltage	V_{IO} (FR)			0	0.3	V
Hysteresis width	V_{IS} (FR)		0.15	0.3	0.45	V
High level input current	I_{IH} (FR)	VF/R = VREG	25	45	65	μA
Low level input current	I_{IL} (FR)	VF/R = 0V	-2	0	+2	μA
FAULT Pin						
Drive stop voltage	VFOF		0		0.5	V
Drive start voltage	VFON		3.0		VREG	V
Input open voltage	V_{IO} (FLT)		4.6	VREG		V
High level input current	I_{IH} (FLT)	VFAULT=VREG		0	10	μA
Low level input current	I_{IL} (FLT)	VFAULT=0V	-200	-160	-120	μA
ADP1 Pin (drive phase adjustment)						
Minimum lead angle	Vadp01	VADP1 = 0V		0	2	Deg
Maximum lead angle	Vadp16	VADP1 = VREG	56	58		Deg
Current ratio with the ADP2 pin current	ADP	VCTL = 5.5V, IADP1/IADP2	1.8	2	2.2	A/A
ADP2 Pin (drive phase adjustment)						
High level output voltage	VADP2H	VCTL = 5.5V	2.25	2.45	2.65	V
Low level output voltage	VADP2L	VCTL = 1.5V	0		0.3	V
DPL Pin (drive-phase-adjustment limit setting pin)						
Lead angle limit high level voltage	VDPLH		3.3	3.5	3.7	V
Lead angle limit low level voltage	VDPLL		1.3	1.5	1.7	V

4. Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
5. These are design target values and no measurements are made.

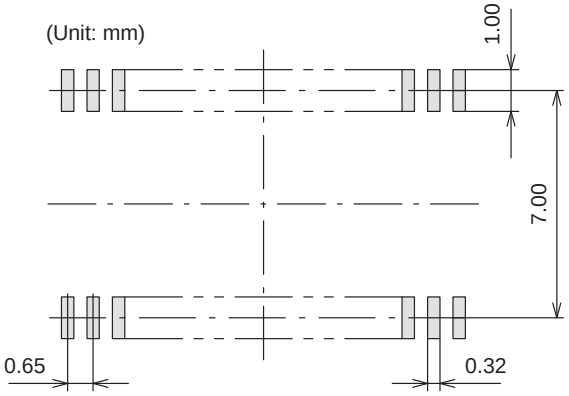
Package Dimensions

unit : mm (typ)

SSOP30 (275mil)
CASE 565AT
ISSUE A



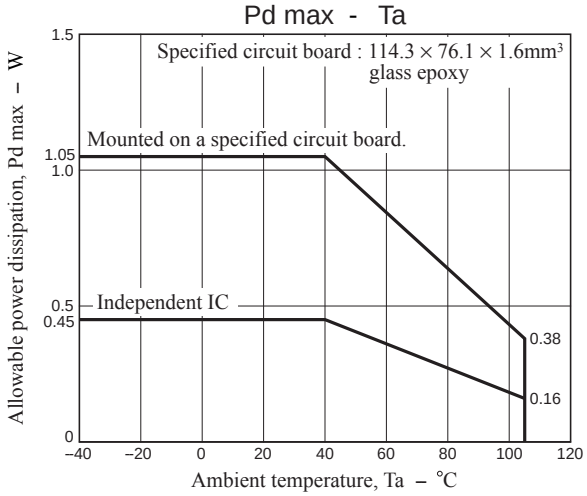
SOLDERING FOOTPRINT*



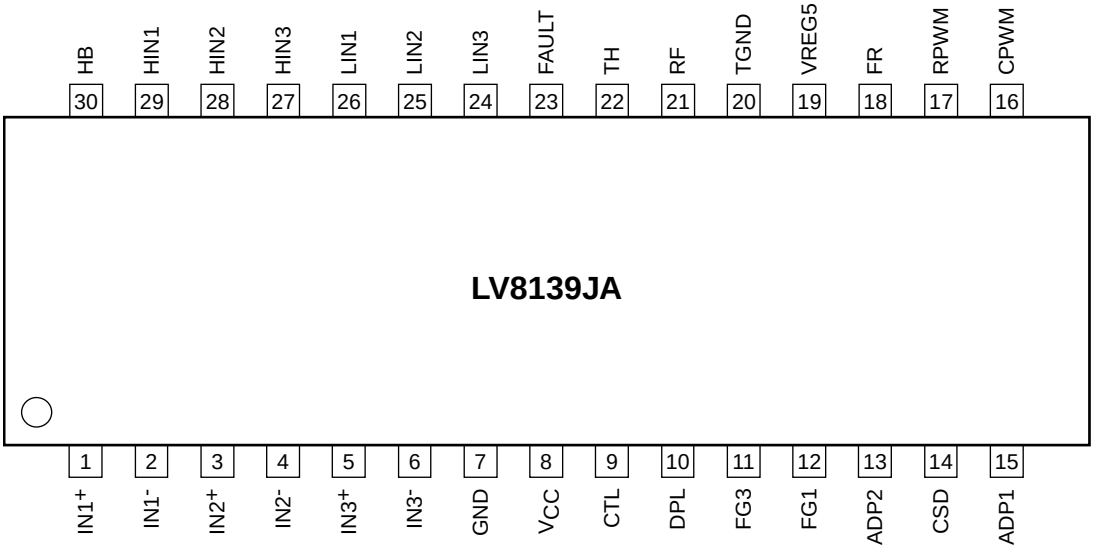
NOTE: The measurements are not to guarantee but for reference only.

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Pdmax-Ta diagram



Pin Assignment



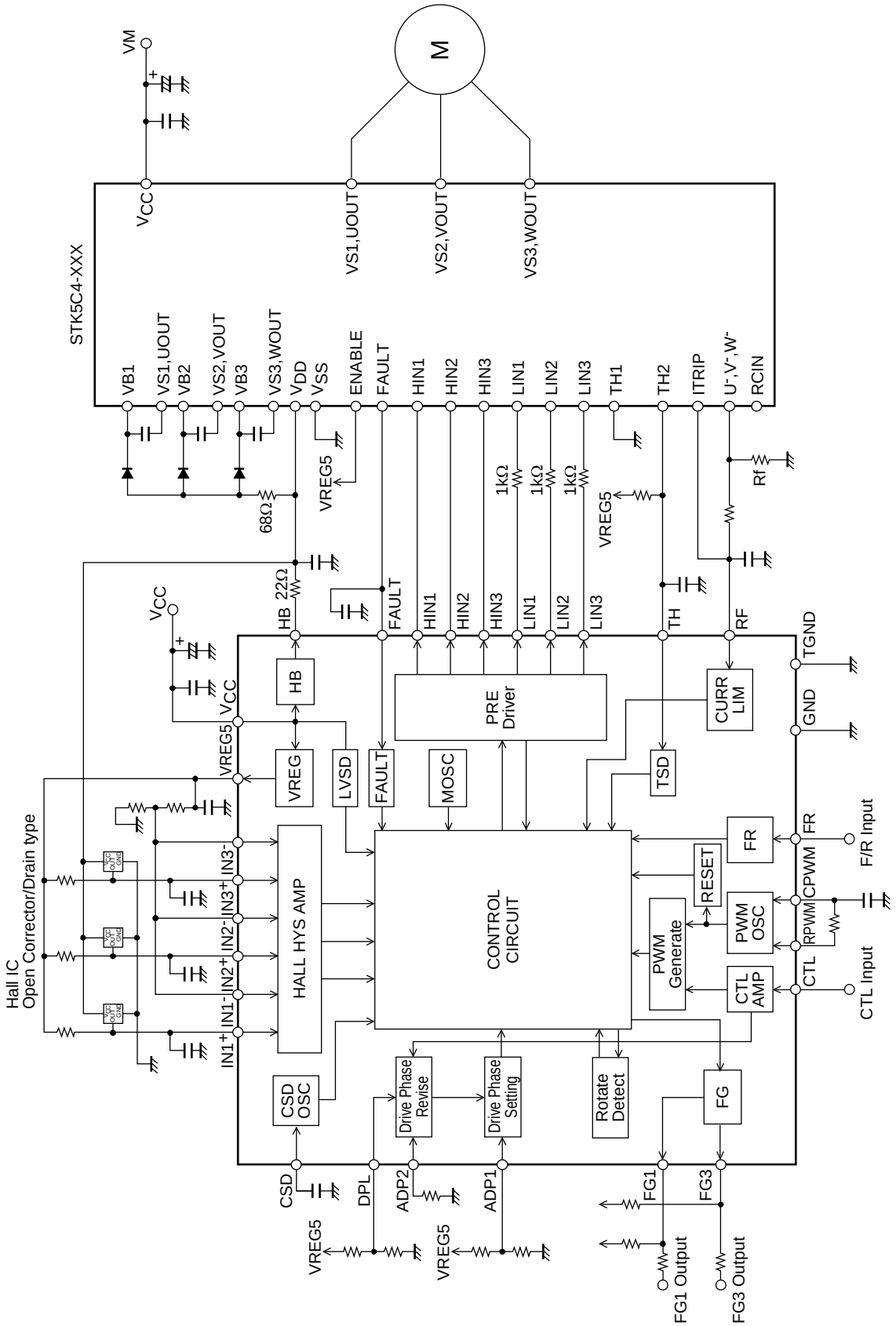
Top view

Sample Application Circuit 1 (Hall IC, HIC)

The Hall IC to be used must be of open-collector or open-drain output type, and it must be pulled up by VREG5.

The type of Hall IC incorporating a pull-up resistor cannot be used.

Furthermore, when using an element that cannot turn off the control power while VM is being applied, the control power must be supplied from the V_{CC} pin rather than from the HB pin.

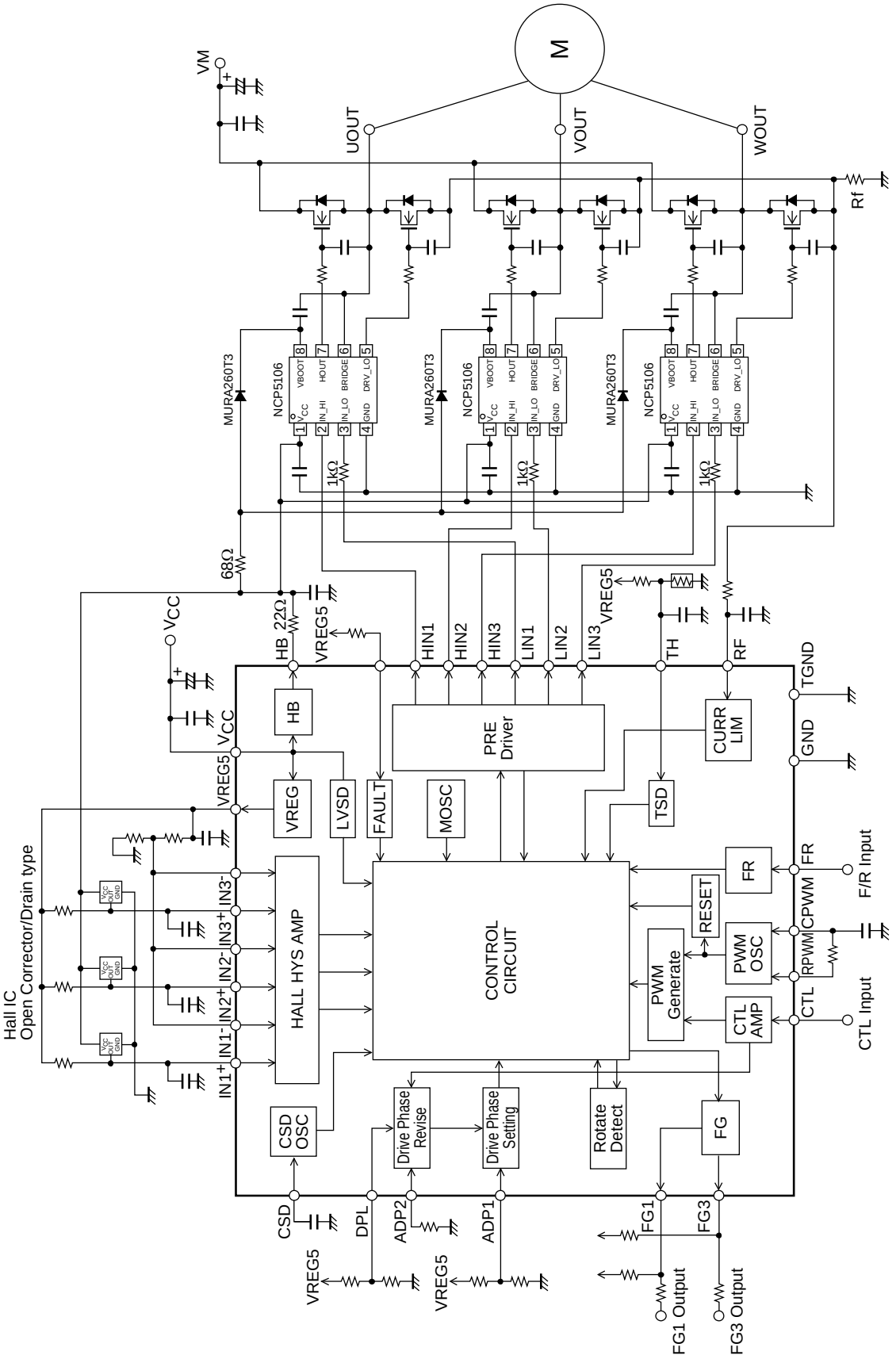


Sample Application Circuit 2 (Hall IC, FET)

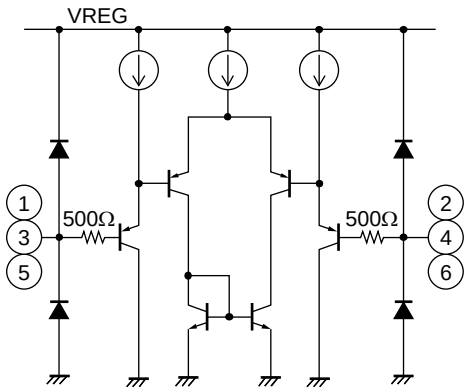
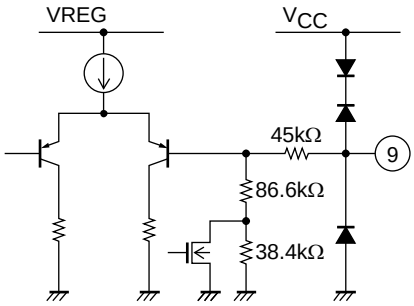
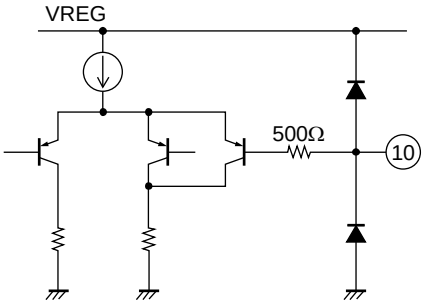
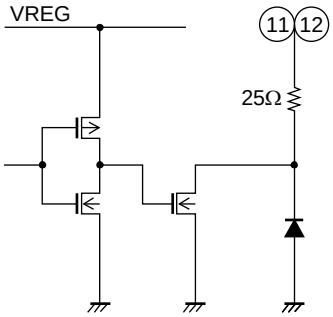
The Hall IC to be used must be of open-collector or open-drain output type, and it must be pulled up by VREG5.

The type of Hall IC incorporating a pull-up resistor cannot be used.

Furthermore, when using a gate driver that cannot turn off the control power while VM is being applied, the control power must be supplied from the V_{CC} pin rather than from the HB pin. An element with a short reverse recovery time must be selected as the output FET.



Pin Functions

Pin No.	Pin Name	Pin function	Equivalent Circuit
1 2 3 4 5 6	$IN1^+$ $IN1^-$ $IN2^+$ $IN2^-$ $IN3^+$ $IN3^-$	Hall signal input pins. The high state is when IN^+ is greater than IN^-, and the low state is the reverse. An amplitude of at least 100mVp-p (differential) is desirable for the Hall signal inputs. If noise on the Hall signals is a problem, insert capacitors between IN^+ and IN^- pins. If input is provided from a Hall IC, fix one side of the inputs (either the "+" or "-" side) at a voltage within the common-mode input range (0.3V to VREG-1.8V), and use the other input side as an input over the 0V to VREG range.	
7	GND	Ground pin of the control circuit block.	
8	V_{CC}	Power supply pin for control. Insert a capacitor between this pin and ground to prevent the influence of noise, etc.	
9	CTL	Control input pin. When CTL pin voltage rises, the IC changes the output signal PWM duty to increase the torque output. In sine wave mode, Nch FET (in equivalent circuit diagram) OFF In 120-degree current-carrying mode, Nch FET ON	
10	DPL	Setting pin for drive phase adjustment limit. This pin is used to limit the lead angle of the drive phase. The lead angle is limited to zero degrees when the voltage is 1.5V or lower and the limit is released when the voltage is 3.5V or higher.	
11 12	FG3 FG1	FG3 : 3-Hall FG signal output pin. 8-pole motor outputs 12 FG pulses per one rotation. In power saving mode, high-level is output. FG1 :1-Hall FG signal output pin. 8-pole motor outputs 4 pulses per one rotation. In power saving mode, high-level is output.	

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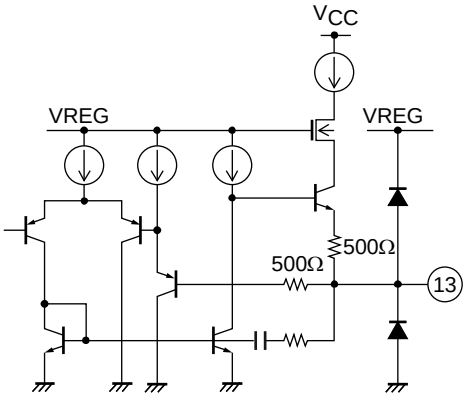
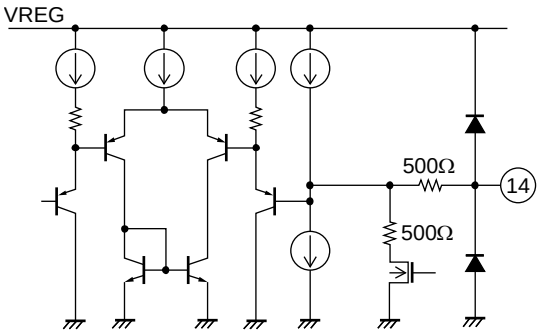
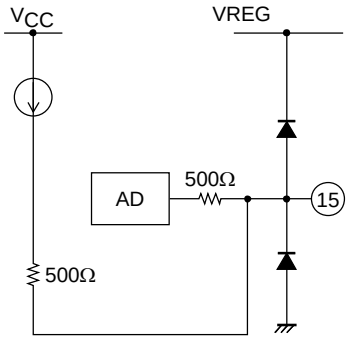
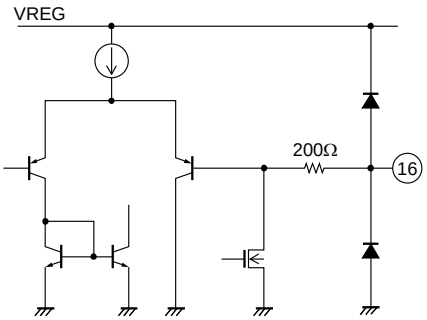
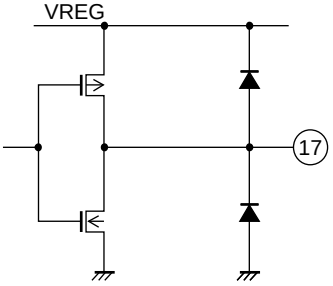
Pin No.	Pin Name	Pin function	Equivalent Circuit
13	ADP2	Setting pin for phase drive correction. This pin sets the amount of correction made to the lead angle according to the CTL input. Insert a resistor between this pin and ground to adjust the amount of correction.	
14	CSD	Pin to set the operating time of the motor constraint protection circuit. Insert a capacitor between this pin and ground. Connect this pin to ground when the constraint protection circuit is not going to be used.	
15	ADP1	Drive phase adjustment pin. The drive phase can be advanced from 0 to 58 degrees during 180-degree current carrying drive. The lead angle becomes 0 degrees when 0V is input and 58 degrees when VREG is input.	
16	CPWM	Triangle wave oscillation pin for PWM generation. Insert a capacitor between this pin and ground and a resistor between this pin and RPWM for triangle wave oscillation.	
17	RPWM	Oscillation pin for PWM generation. Insert a resistor between this pin and CPWM.	

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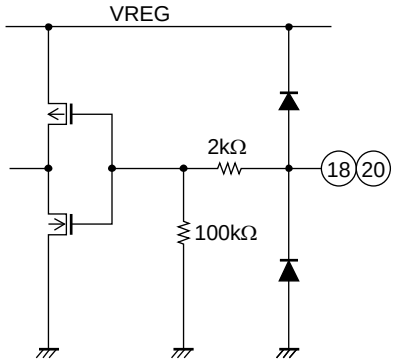
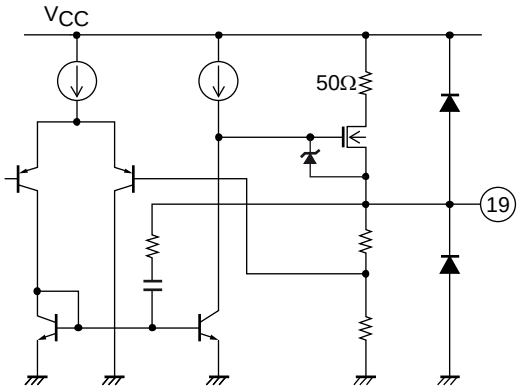
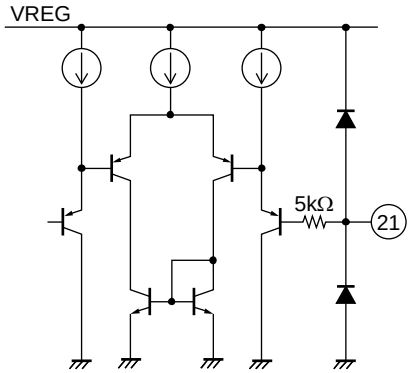
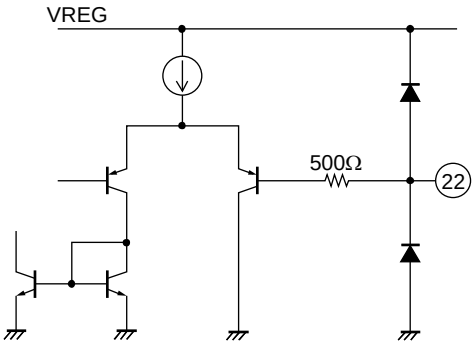
Pin No.	Pin Name	Pin function	Equivalent Circuit
18 20	FR TGND	FR Forward/reverse rotation setting pin. A low-level specifies forward rotation and a high-level specifies reverse rotation. This pin is held low when open. TGND Test pin. Connect this pin to ground.	
19	VREG5	5V regulator output pin (control circuit power supply). Insert a capacitor between this pin and ground for power stabilization. 0.1μF or so is desirable.	
21	RF	Output current detection pin. This pin is used to detect the voltage across the current detection resistor (Rf). The maximum output current is determined by the equation I_{OUT} = 0.25V/Rf.	
22	TH	Thermistor connection pin. The thermistor detects heat generated from HIC and turns off the drive output when an overheat condition occurs. All the HIN/LIN output pins are set to low at a pin voltage of 0.6V or less. * For further details, refer to “Description of LV8139JA.”	

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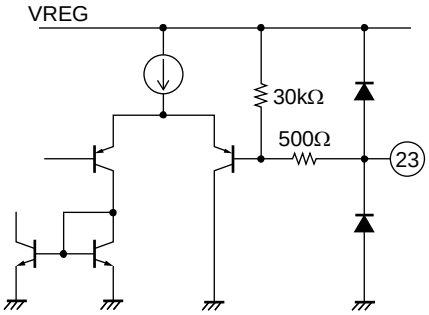
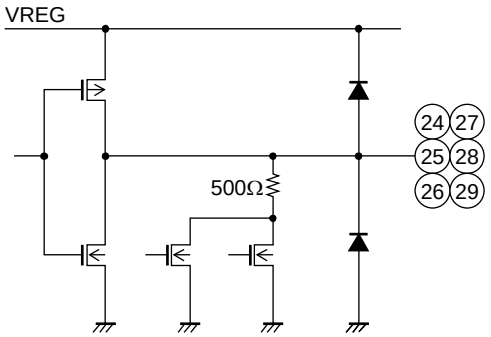
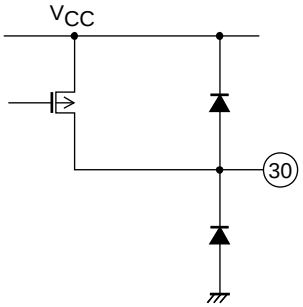
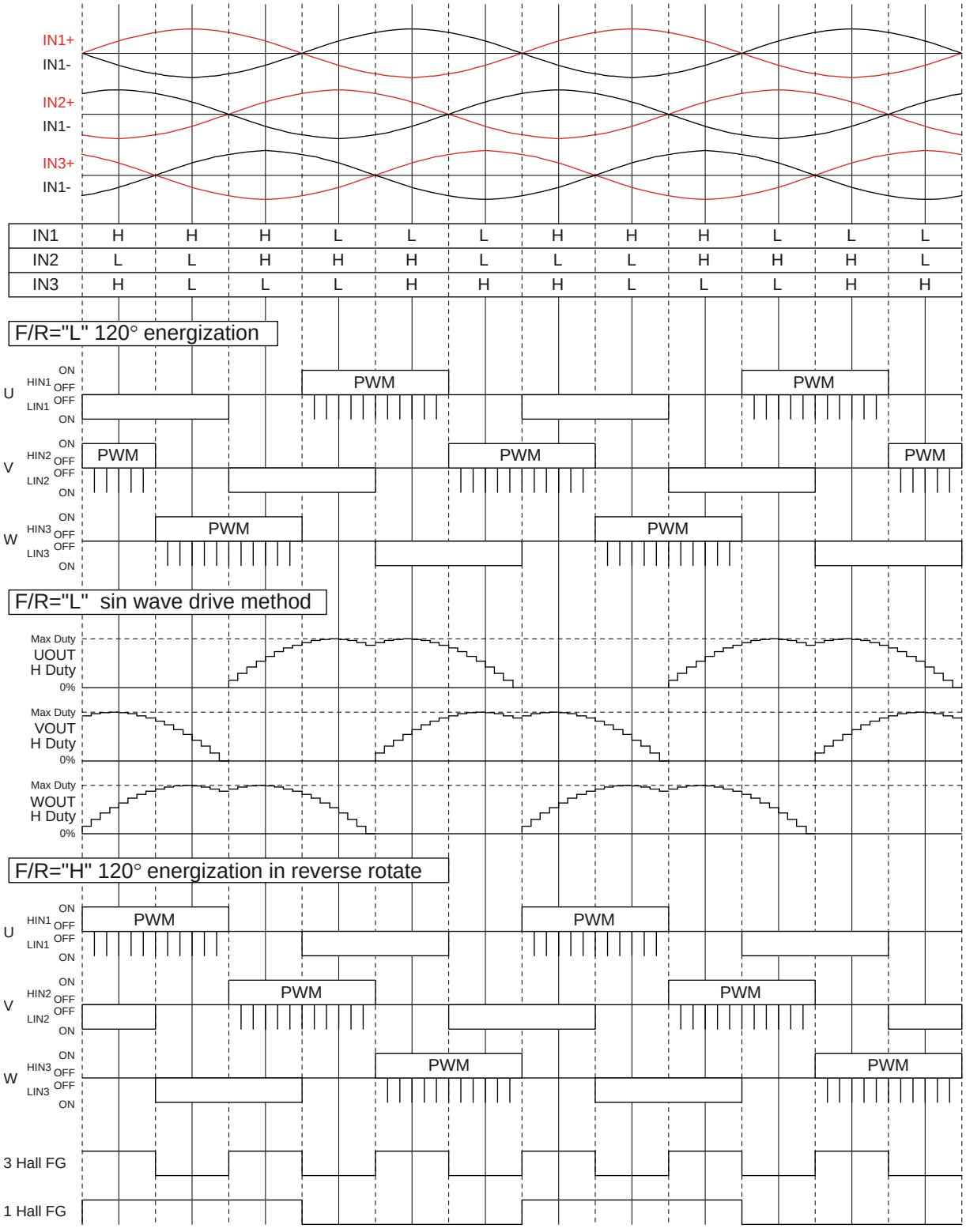
Pin No.	Pin Name	Pin function	Equivalent Circuit
23	FAULT	HIC protection signal input pin. This pin accepts an error mode detection signal generated by the HIC side. With a low-level input, the error mode detection condition is established, and all the HIN/LIN output pins are set to low. * For further details, refer to “Description of LV8139JA.”	
24 25 26 27 28 29	LIN3 LIN2 LIN1 HIN3 HIN2 HIN1	LIN1, LIN2, and LIN3 : L side drive signal output pin. Generate 0 to VREG push-pull outputs. HIN1, HIN2, and HIN3 : H side drive signal output pin. Generate 0 to VREG push-pull outputs.	
30	HB	Hall bias HIC power supply pin. Insert a capacitor between this pin and ground. This pin is set to high-impedance state in power saving mode. By supplying Hall bias and HIC power using this pin, the power consumption by Hall bias and HIC in power saving mode can be reduced to zero.	

Timing Chart (IN = “H”indicates the state in which IN^+ is greater than IN^-.)
(1) F/R pin = L

Normal Hall input Lead Angle=0°

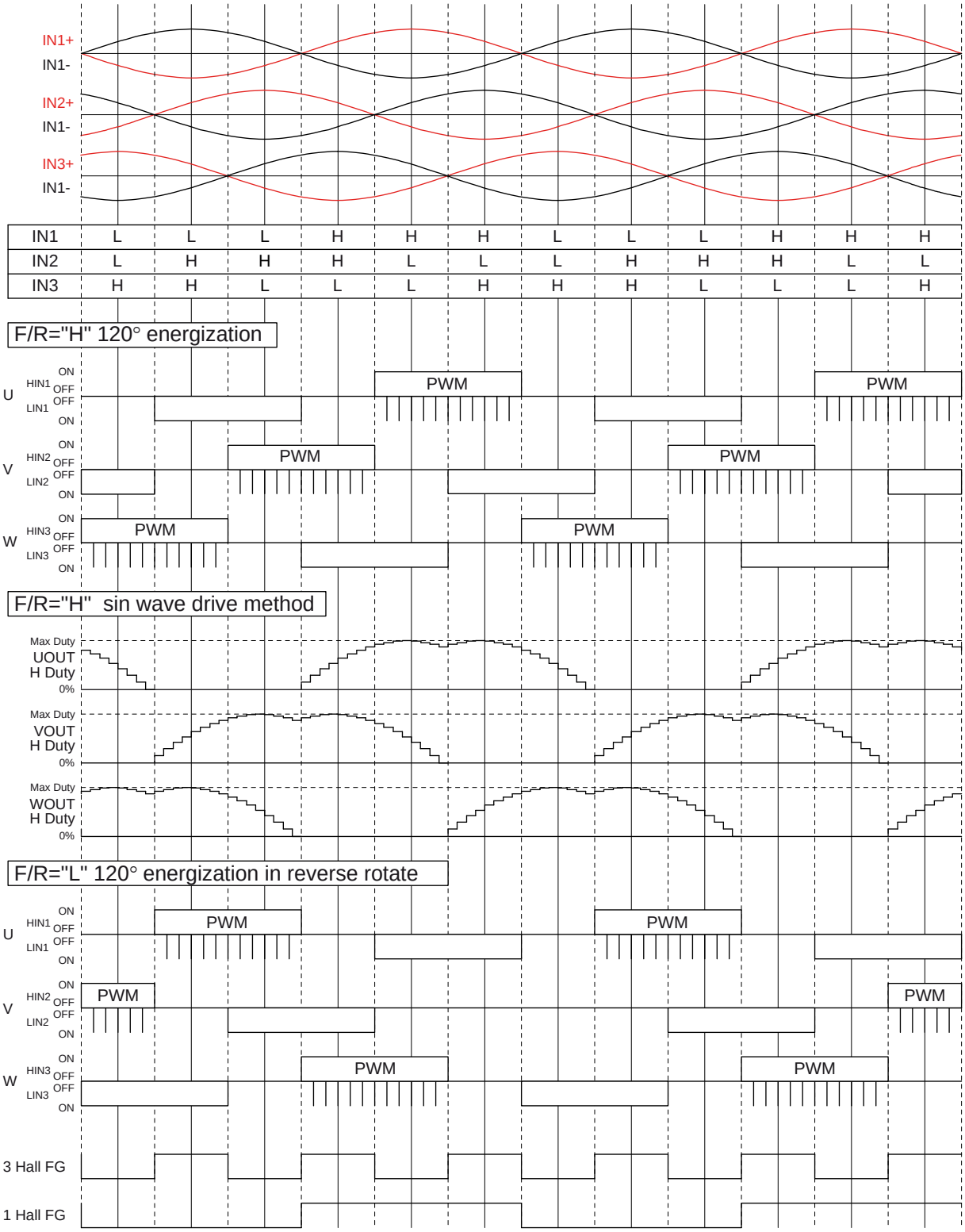


The energization is switched to 120° wher 3 Hall FG frequency is 5.15Hz (typ) or lower
A direction of rotation is detected from Hall signal according to F/R pin input

If the motor rotates in reverse against F/R pin input 120° energization is maintained forcibly

(2) F/R pin = H

Reverse Hall input Lead Angle=0°



The energization is switched to 120° wher 3 Hall FG frequency is 5.15Hz (typ) or lower
A direction of rotation is detected from Hall signal according to F/R pin input

If the motor rotates in reverse against F/R pin input 120° energization is maintained forcibly

Functional Description

• Basic operation of 120-degree ⇔ Sine wave current-carrying switching

At startup, this IC starts at 120-degree current-carrying. The current-carrying is switched to sine wave when the 3-Hall FG frequency is 5.15Hz (typ) or above and the rising edge of the IN2 signal has been detected twice in succession.

○ Concerning the Hall signal input sequence

This IC controls the motor rotation direction commands and Hall signal input sequence in order to set the lead angle. If the motor rotation direction commands and Hall signal input sequence do not conform to what is shown on the timing chart, the motor is driven by 120-degree current-carrying. Shown below are two Hall signal input sequences.

Sequence 1 : When the Hall signal has been input with the following logic

IN1	H		H		H		L		L		L
IN2	L	→	L	→	H	→	H	→	H	→	L
IN3	H		L		L		L		H		H

When F/R pin input is high → 120-degree current-carrying
When F/R pin input is low → 180-degree current-carrying

Sequence 2 : When the Hall signal has been input with the following logic

IN1	H		L		L		L		H		H
IN2	L	→	L	→	H	→	H	→	H	→	L
IN3	H		H		H		L		L		L

When F/R pin input is high → 180-degree current-carrying
When F/R pin input is low → 120-degree current-carrying

• CTL pin input

a) Power-saving mode $V_{CTL} < V_{IL}$ (0.95V : typ)

• $L_{IN}1$ to $L_{IN}3$ and $H_{IN}1$ to $H_{IN}3$ outputs all set to low

• I_{CC} = 0, HB pin = OFF

The power consumption of the IC can now be set to 0, and the power consumption of the Hall element connected to the HB pin and the output block can also be set to 0.

b) Standby mode While stopped: $V_{IL} < V_{CTL} < V_{IM}1$ (2.33V: typ); while running: $V_{IL} < V_{CTL} < V_{IM}2$ (2.1V: typ)

The $U_{IN}1$ to 3 outputs are set to low, and the bootstrap charge pulse (pulse width: 2.5μs: design target) is output to the $L_{IN}1$ to 3 outputs in preparation for drive start.

c) Drive mode At drive start: $V_{IM}1 < V_{CTL} < 7V$; during drive: $V_{IM}2 < V_{CTL} < 7V$ (V_{IH} 4.7V: typ)

The motor is driven at the PWM duty ratio that corresponds to V_{CTL}. When V_{CTL} is increased, the PWM duty ratio increases, and the maximum duty ratio is established at "V_{IH}."

d) Test mode $8.5V < V_{CTL} < V_{CC}$

When the CTL pin voltage is 8V or higher, the IC enters the test mode, and the motor is driven at the 120-degree current-carrying and maximum duty* ratio.

* When the PWM oscillation frequency setting is 17kHz, the maximum duty ratio in the 120-degree current carrying mode is 88% (typ).

• The CTL pin is pulled down by 170kΩ (120-degree mode) : Typ, 131.6kΩ (sine wave mode) : typ inside the IC. Caution is required when the control input voltage input is subjected to resistance division, for example.

• Bootstrap capacitor initial charging mode

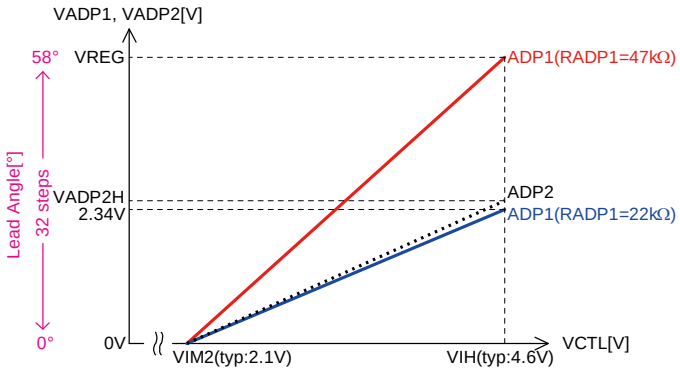
When the mode is switched from the power-saving mode to the standby mode and then to the drive mode, the IC enters the bootstrap capacitor charging mode ($H_{IN}1$, $H_{IN}2$, $H_{IN}3$ pins = L $L_{IN}1$, $L_{IN}2$, $L_{IN}3$ pins = H 4.55ms typ) in order to charge the bootstrap capacitor.

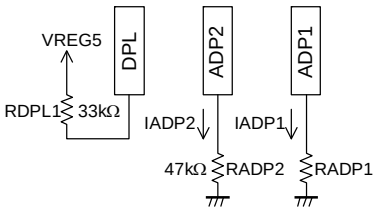
• Drive phase adjustment

During 180-degree current-carrying drive, any lead angle from 0 to 58 degrees can be set using the ADP1 pin voltage (lead angle control). This setting can be adjusted in 32 steps (in 1.875-degree increments) from 0 to 58 degrees using the ADP1 pin voltage, and it is updated every Hall signal cycle (it is sampled at the rising edge of the IN3 input and updated at its falling edge).

A number of lead angle adjustments proportionate to the CTL pin voltage can be undertaken by adjusting the resistance levels of resistors connected to the ADP1 pin, ADP2 pin and DPL pin. When these pins are not going to be used, reference must be made to section 4.5, and the pins must not be used in the open status. Furthermore, a resistance of 47kΩ or more must be used for the resistor (RADP2) that is connected to the ADP2 pin.

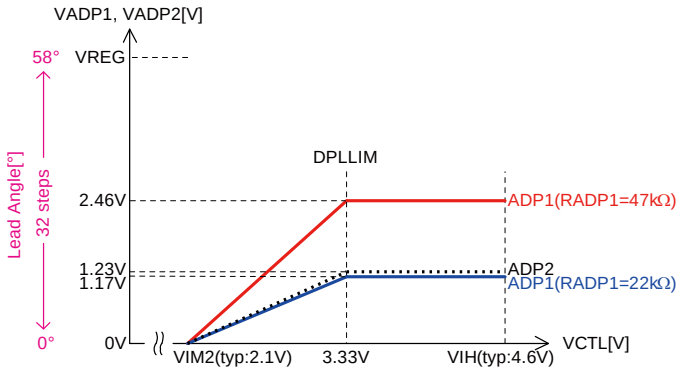
1. The slopes of V_{CTL} and VADP1 can be adjusted by setting the resistance level of the resistor (RADP1) connected to ADP1 (pin 15).

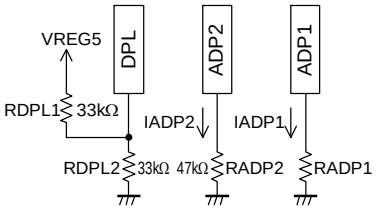




VADP2=(VCTL-VIM2)×(2.5/(VIH-VIM2))
=(VCTL-2.1V)×(2.5/(4.6V-2.1V))
IADP2=VADP2/RADP2
IADP1=IADPR×IADP2
VADP1=IADP1×RADP1

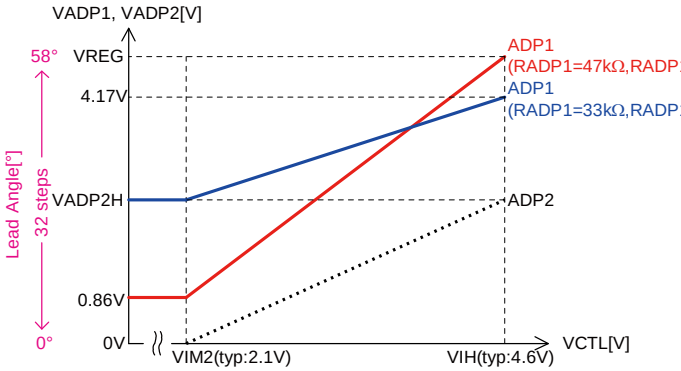
2. The ADP2 pin rise can be halted (a limit on the lead angle adjustment can be set by means of the CTL voltage) by setting DPL (pin 10).

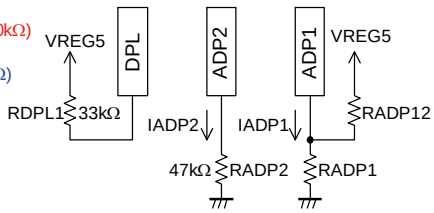




VADP2=(VCTL-VIM2)×(2.5/(VIH-VIM2))
IADP2=VADP2/RADP2
IADP1=IADPR×IADP2
VADP1=IADP1×RADP1
DPLLIM=VDPL×1.36

3. The offset and slope can be adjusted as desired by setting RADP1 and RADP12 of ADP1 (pin 15). (It is also possible to set a limit on the lead angle adjustment by means of the CTL voltage by setting DPL.)





VADP2=(VCTL-VIM2)×(2.5/(VIH-VIM2))
IADP2=VADP2/RADP2
IADP1=IADPR×IADP2
VADP1=((RADP1×RADP12)/(RADP1+RADP12))×IADP1
+(RADP1/(RADP1+RADP12))×VREG

4. When the lead angle is not adjusted
ADP1 pin: shorted to ground; ADP2 pin and DPL pin: pulled down to ground using the resistors

5. When the lead angle is not adjusted by means of the CTL pin voltage (for use with a fixed lead angle)
ADP1 pin: lead angle setting by resistance division from VREG5; ADP2 pin and DPL pin: pulled down to ground by the resistors

Description of LV8139

1. Current Limiter Circuit
   The current limiter circuit limits the output current peak value to a level determined by the equation I = V_{RF}/Rf (where V_{RF} = 0.25V typ, Rf is the value of the current detection resistor). The current limiter operates by reducing the H_{IN} output on duty to suppress the current.
   The current limiter circuit detects the reverse recovery current of the diode due to PWM operation. To assure that the current limiting function does not malfunction, its operation has a delay of approx. 1μs. If the motor coils resistance or a low inductance, current fluctuation at startup (when there is no back electromotive force in the motor) will be rapid. The delay in this circuit means that at such times the current limiter circuit may operate at a point well above the set current. Application must take this increase in the current due to the delay into account when the current limiter value is set.

2. Power Saving Circuit (CTL pin)
   This IC goes into the power saving mode that stops operation of all the circuits to reduce the power consumption. If the HB pin is used for the Hall element bias and the output block, the current consumption in the power-saving mode is zero.

3. Hall Input Signal
   Signals with an amplitude in excess of the hysteresis is required for the Hall inputs. However, considering the influence of noise and phase displacement, an amplitude of over 100mV is desirable.
   If noise disrupts the output waveform, this must be prevented by inserting capacitors or other devices across the Hall inputs. The Hall inputs are used by the circuit inside the IC as decision signals so if noise enters, a malfunction occurs in the operation.
   Although the circuit is designed to tolerate a certain amount of noise, care is required.
   Furthermore, when the Hall signal amplitude has changed as a result of a change in temperature, the drive phase may possibly shift due to the Hall amplifier hysteresis. It is the user who is responsible for giving due consideration to this aspect. Use of a Hall IC is recommended unless there is a reason not to use one.
   If all three phases of the Hall input signal go to the same input state (HHH or LLL), all the HIN/LIN outputs are set to low.
   If the outputs from a Hall IC are used, fix one side of the inputs (either the "+" or "−" side) at a voltage within the common-mode input voltage range (0.3V to VREG−1.8V), and use the other input side as an input over the 0V to VREG range.

4. Constraint Protection Circuit
   A constraint protection circuit is incorporated in order to protect the output elements and motor when the motor is constrained. The circuit is activated when the Hall signal is not switched for a specific period of time when the motor is in operation. The counter is reset each time the motor rotates 360 degrees in terms of the electrical angle.
   All the H_{IN} and L_{IN} outputs are set to the low level when the constraint protection circuit is in operation. This time is determined by the capacitance of the capacitor connected to the CSD pin.

   Oscillation time of CSD pin (1 pulse) T = | (V_{OH}-V_{OL})/ICHG1 | × C (μF) + | (V_{OH}-V_{OL})/ICHG2 | × C (μF)
   Constraint protection detection time T1 (s) = T × 256 (count)
   Constraint protection time T2 (s) = T × 2816 (count)

   When a 0.022μF capacitor is attached, T = 8.36ms, T1 = 2.14s and T2 = 23.54s are established as the typical ratings. After the motor has been constrained, the constraint protection state is established at 2.14 (s), and then after 23.54 (s) has elapsed, the constraint protection circuit is reset automatically. A time that provides some leeway in the motor start time that factors in any fluctuations must be selected as the setting.

   Conditions for releasing the constraint protection state other than by automatic resetting:
   - When CTL pin voltage < V_{IM}2 input → protection release and CSD count reset
   - When the low level is detected on the TH pin → protection release and CSD count reset
   - When FR has been switched → protection release and CSD count reset
   - When TSD protection is detected → CSD count stop

5. Power Supply Stabilization
   Since this IC adopts a switching drive technique, the power-supply line level can be disrupted easily. Thus capacitors large enough to stabilize the power supply voltage must be inserted between the V_{CC} pins and ground. If the electrolytic capacitors cannot be connected close to their corresponding pins, ceramic capacitors of about 0.1μF must be connected near these pins.
   If diodes are inserted in the power-supply line to prevent destruction of the device when the power supply is connected with reverse polarity, the power supply line levels will be even more easily disrupted, and even larger capacitors must be used.

6. VREG Stabilization
Connect a capacitor with a capacitance of 0.1μF or more between VREG5 and ground in order to stabilize the VREG voltage that is the power supply of the control circuit.
The ground lead of that capacitor must be located as close as possible to the control system ground (SGND) of the IC.

7. Forward/Reverse Switching (F/R pin)
Switching between forward rotation and reverse rotation must not be undertaken while the motor is running.

8. TH Pin
The TH pin must normally be pulled up to VREG5 for use. When this pin has been set to low, all the H_{IN}/L_{IN} outputs are set to low. When reset is initiated, the bootstrap initial charging mode is established.

9. FAULT Pin
The FAULT pin must normally be pulled up to VREG5 for use. When this pin has been set to low, all the H_{IN}/L_{IN} outputs are set to low. When reset is initiated, the bootstrap initial charging mode is established.
All the outputs are set to low. In addition, the FG1/FG3 output goes off, too. When reset is initiated, the bootstrap initial charging mode is established.

10. PWM Frequency Setting
$fCPWM \approx 1/(1.7CR)$
Components with good temperature characteristics must be used.
An oscillation frequency of about 17kHz is obtained when a 2200pF capacitor and 15kΩ resistor are used.
If the PWM frequency is too low, switching noise will be heard from the motor; conversely, if it is too high, the output power loss will increase. For this reason, a frequency between 15kHz and 30kHz or so is desirable. The capacitor ground must be connected as close as possible to the control system ground (SGND pin) of the IC to minimize the effects of the outputs.
If there are no fluctuations in the capacitance or resistance of the external capacitors or resistors and only the IC fluctuations are to be considered, an actual capability of ±3% can be expected.

11.Concerning the power-raising operation
This IC provides sine wave PWM drive so it performs operations similar to synchronous rectification. These operations are such that current is sometimes returned to the motor power supply side depending on the conditions of use. For instance, this may happen when:

- The drive phase is shifted.
- The motor has been suddenly accelerated.
- The output duty ratio has been decreased sharply while the motor is running.

If the output duty ratio has been decreased sharply, it is highly likely that current will return to the motor power supply.
The extent to which the motor supply voltage increases differs depending on the size of the capacitors used in the product that incorporates the motor, the size of the capacitor inserted between the motor power supply and ground on the motor circuit board and the motor used; as such, it is the user who is responsible for giving due consideration to this aspect.
It is necessary to take remedial action such as increasing the capacitance of the capacitors or reducing the speed at which the duty ratio will be reduced when the motor supply voltage rises to ensure that the maximum withstand voltage of the element used for output is not exceeded.